

## Low Power, High Voltage SPST Analog Switches

### **DESCRIPTION**

The DG447, DG448 dual are supply single-pole/single-throw (SPST) switches. On resistance is 25  $\Omega$  maximum and flatness is 2.2  $\Omega$  max over the specified analog signal range. These analog switches were designed to provide high speed, low error switching of precision analog signals. The primary application areas are in the routing and switching in telecommunications and test equipment. Combining low power, low leakages, low on-resistance and small physical size, the DG477, DG448 are also ideally suited for portable and battery powered industrial and military equipment.

The DG477 has one normally closed switch, while the DG448 switch is normally open. They operate either from a single 7 V to 36 V supply or from dual  $\pm$  4.5 V to  $\pm$  20 V supplies. They are offered in the very popular, small TSOP6 package.

#### **BENEFITS**

- Wide dynamic range
- · Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing
- Reduced board space
- · Improved reliability

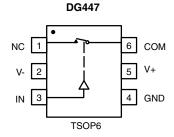
### **FEATURES**

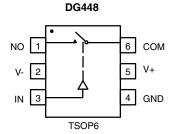
- ± 15 V analog signal range
- On-resistance R<sub>DS(on)</sub>: 25 Ω max.
- Fast switching action ton: 100 ns
- V<sub>L</sub> logic supply not required
- TTL CMOS input compatible
- · Rail to rail signal handling
- Dual or single supply operation
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **APPLICATIONS**

- Precision test equipment
- · Precision instrumentation
- · Communications systems
- PBX, PABX systems
- Audio equipment
- · Redundant systems
- · PC multimedia boards
- · Hard disc drives

### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**





TRUTH TABLE					
LOGIC	DG447	DG448			
0	On	Off			
1	Off	On			

#### Note

• Logic "0" ≤ 0.8 V Logic "1" ≥ 2.4 V

Device Marking: DG447DV = G5xxx DG448DV = G6xxx

ORDERING INFORMATION					
TEMP. RANGE PACKAGE PART NUMBER					
DG447, DG448					
40 °C to 195 °C	6 nin TCOD	DG447DV-T1-E3			
-40 °C to +85 °C	6-pin TSOP	DG448DV-T1-E3			

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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)					
PARAMETER		LIMIT	UNIT		
V+		44			
GND		25	V		
Digital inputs <sup>a</sup> , V <sub>NO/NC</sub> , V <sub>COM</sub>		(V-) - 2 to $(V+)$ + 2 or 30 mA, whichever occurs first	•		
Continuous current (any terminal)		30	m A		
Current (NO or NC or COM) pulsed a	t 1 ms, 10 % duty cycle	100	mA		
Storage temperature		-65 to +150	°C		
Power dissipation (package) <sup>b</sup>	6-pin TSOP <sup>c</sup>	570	mW		

- a. Signals on NO, NC, COM, or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current
- b. All leads welded or soldered to PC boardc. Derate 7 mW/°C above 70 °C

SPECIFICATIONS <sup>a</sup>							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED	TEMP.b	D SUFFIX -40 °C TO +85 °C			UNIT
		V+ = 15 V, V- = -15 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup>		MIN. d	TYP. <sup>c</sup>	MAX. d	
Analog Switch						•	
Analog signal range <sup>e</sup>	V <sub>ANALOG</sub>		Full	-15	-	15	V
Drain-source on-resistance	R <sub>ON</sub>	I <sub>NO/NC</sub> = 10 mA, V <sub>COM</sub> = 10 V,	Room	-	17	25	
Diam-source on-resistance	TION	V+ = 13.5 V, V- = -13.5 V	Full	-	-	30	Ω
On-resistance flatness	R <sub>ON</sub>	$I_{NO/NC} = 10 \text{ mA}, V_{COM} = \pm 5 \text{ V}, 0 \text{ V},$	Room	-	8.0	2.2	52
On-resistance natness	flatness	V+ = 13.5 V, V- = -13.5 V	Full	-	-	3	
	1		Room	-1	-0.1	1	
Switch off lookage ourrent	I <sub>NO/NC(off)</sub>	V+ = 16.5, V- = -16.5 V,	Full	-10	-	10	
Switch off leakage current		$V_{COM} = \pm 15.5 \text{ V},$ $V_{NO/NC} = -/+ 15.5 \text{ V}$	Room	-1	-0.1	1	^
	I <sub>COM(off)</sub>	10000	Full	-10	-	10	nA
		V+ = 16.5 V, V- = -16.5 V,	Room	-1	-0.1	1	1
Channel on leakage current	I <sub>COM(on)</sub>	$V_{COM} = V_{NO/NC} = \pm 15.5 \text{ V}$	Full	-10	-	10	
Digital Control							
Input, high voltage	I <sub>INH</sub>		Full	2.4	-	-	.,
Input, low voltage	I <sub>INL</sub>		Full	-	-	0.8	V
Input capacitance e	C <sub>IN</sub>		Room	-	5	-	pF
Input current	I <sub>IN</sub>	V <sub>IN</sub> = 0 V or 5 V		-1	-	1	μΑ
Dynamic Characteristics							
Turn on time			Room	-	100	130	- ns
Turn-on time	t <sub>on</sub>	$R_L = 300 \Omega, C_L = 35 pF$	Full	-	-	140	
T aff bins a		$V_{NO/NC} = \pm 10 \text{ V}$	Room	-	50	95	
Turn-off time	t <sub>off</sub>		Full	-	-	110	
Charge injection <sup>e</sup>	Q	$C_L$ = 10 nF, $V_{gen}$ = 0 V, $R_{gen}$ = 0 $\Omega$	Room	-	10	-	рС
Off-isolation e	OIRR	$C_L = 5 \text{ pF}, R_L = 50 \Omega, f = 1 \text{ MHz}$	Room	-	-72	-	dB
Source off capacitance e	C <sub>S(off)</sub>	C 4 MIL	Room	-	19	-	
Drain off capacitance e	C <sub>D(off)</sub>	f = 1 MHz	Room	-	8	-	pF
Channel on capacitance e	C <sub>D(on)</sub>	f = 1 MHz	Room	-	30	-	
Power Supplies							
Positive supply current	oly current I+		Room	-	16	30	
		V+ = 16.5 V, V- = -16.5 V,	Full	-	-	50	
Negative aupply assess	1	$V_{IN} = 0 \text{ V or } 5 \text{ V}$	Room	-1	-0.02	-	– μA –
Negative supply current	I-		Full	-10	-	-	



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SPECIFICATIONS <sup>a</sup>							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED	TEMP.b	D SUFFIX - 40 °C TO +85 °C			UNIT
		V+ = 12 V, V- = 0 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup>		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog signal range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0	-	12	V
Drain-source on-resistance	В	I <sub>NO/NC</sub> = -10 mA, V <sub>COM</sub> = 8 V,	Room	-	32	45	Ω
Drain-source on-resistance	R <sub>ON</sub>	V+ = 10.8 V	Full	-	-	60	
On-resistance flatness	R <sub>ON</sub> flatness	I <sub>NO/NC</sub> = 10 mA, V <sub>COM</sub> = 2 V, 6 V, 8 V	Room	-	2	6	
On-resistance natness		V+ = 10.8 V	Full	-	-	8	
Dynamic Characteristics							
Turn-on time	t <sub>on</sub>		Room	-	140	175	
Turn-on time		$V_{NO, NC} = \pm 10 \text{ V}, R_1 = 300 \Omega, C_1 = 35 \text{ pF}$	Full	-	-	225	,,,
Turn-off time	t <sub>off</sub>	$V_{NO, NC} = \pm 10 \text{ V}, \text{ NL} = 300 \Omega, \text{ CL} = 35 \text{ pF}$	Room	-	50	120	ns
Turri-on time			Full	-	-	150	]
Charge injection e	Q	$C_L = 10 \text{ nF}, V_{gen} = 0 \text{ V}, R_{gen} = 0 \Omega$	Room	-	12	-	рС
Power Supplies							
Positive supply current	I+	V+ = 13.2 V, V <sub>IN</sub> = 0 V, 5 V	Room	-	22	50	μA
	I+	v = 13.2 v, v <sub>IN</sub> = 0 v, 3 v	Full	-	-	75	μΛ

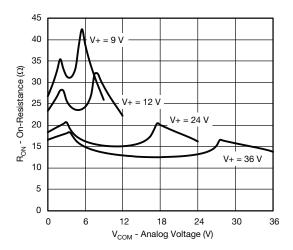
#### **Notes**

- a. Refer to PROCESS OPTION FLOWCHART
- b. Room = 25  $^{\circ}$ C, full = as determined by the operating temperature suffix
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
- e. Guaranteed by design, not subject to production test
- f.  $V_{IN}$  = input voltage to perform proper function

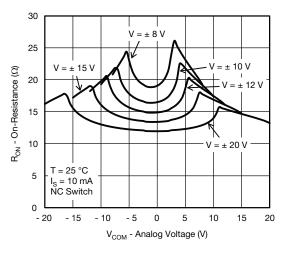
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



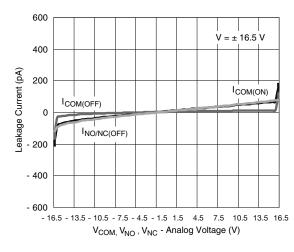
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



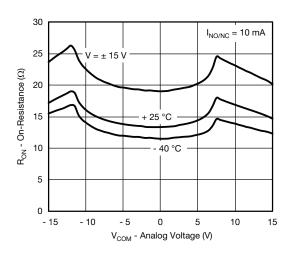
Ron vs. V<sub>COM</sub> and Single Supply Voltage



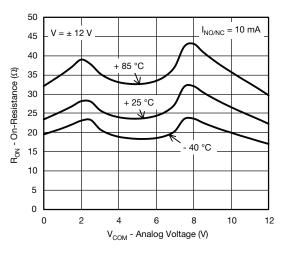
 $R_{ON}$  vs.  $V_{COM}$  and Dual Supply Voltage



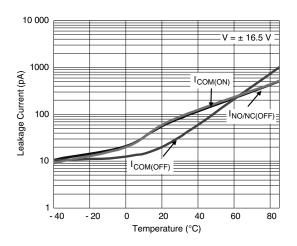
Leakage vs. Analog Voltage



R<sub>ON</sub> vs. Analog Voltage and Temperature



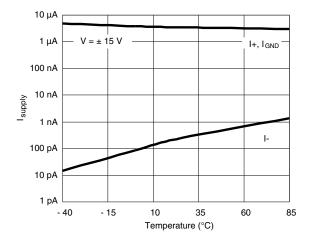
R<sub>ON</sub> vs. Analog Voltage and Temperature



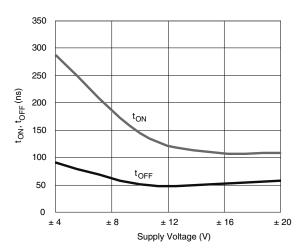
Leakage Current vs. Temperature



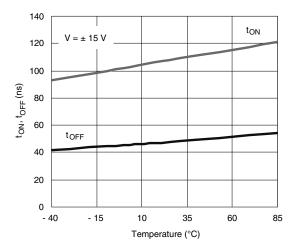
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



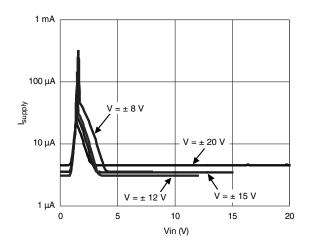
Supply Current vs. Temperature



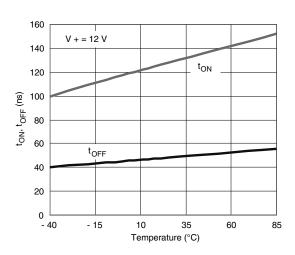
Switching Time vs. Supply Voltages



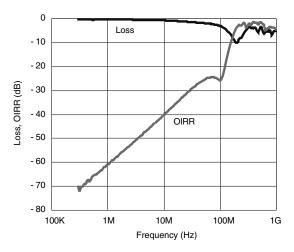
Switching Time vs. Temperature



Supply Current vs. V<sub>IN</sub>



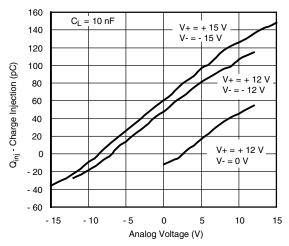
Switching Time vs. Temperature



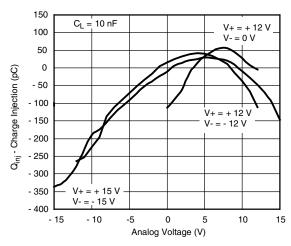
Off Isolation and Insertion Loss vs. Frequency



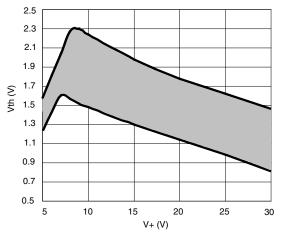
## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Charge Injection vs. Analog Voltage (Measured at COM pin)



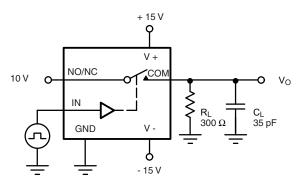
Charge Injection vs. Analog Voltage (Measured at NC or NO pin)



Input Switching Threshold vs. Supply Voltage

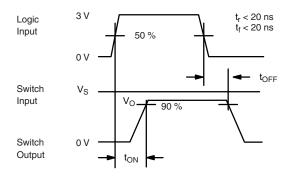
### **TEST CIRCUITS**

V<sub>O</sub> is the steady state output with the switch on.



C<sub>L</sub> (includes fixture and stray capacitance)

$$V_O = V_S$$
 
$$\frac{R_L}{R_L + r_{ON}}$$



Note: Logic input waveform is inverted for switches that have the opposite logic sense.

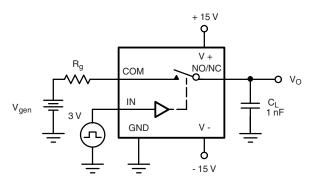
Fig. 1 - Switching Time

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### **TEST CIRCUITS**

 $V_{\text{O}}$  is the steady state output with the switch on.



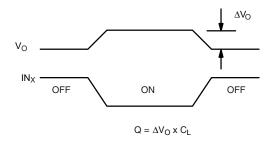
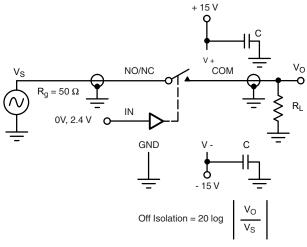


Fig. 2 - Charge Injection



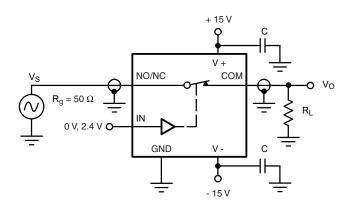


Fig. 3 - Off Isolation

Fig. 4 - Insertion Loss

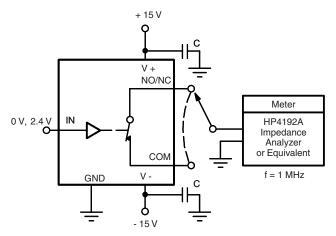


Fig. 5 - Source/Drain Capacitances



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PRODUCT SUMMARY			
Part number	DG447	DG448	
Status code	2	2	
Configuration	SPST x 1, NO	SPST x 1, NO	
Single supply min. (V)	7	7	
Single supply max. (V)	36	36	
Dual supply min. (V)	4.5	4.5	
Dual supply max. (V)	22	22	
On-resistance (Ω)	32	32	
Charge injection (pC)	12	12	
Source on capacitance (pF)	30	30	
Source off capacitance (pF)	8	8	
Leakage switch on typ. (nA)	0.1	0.1	
Leakage switch off max. (nA)	1	1	
-3 dB bandwidth (MHz)	-	-	
Package	TSOP-6	TSOP-6	
Functional circuit / applications	Multi purpose, instrumentation, medical and healthcare	Multi purpose, instrumentation, medical and healthcare	
Interface	Parallel	Parallel	
Single supply operation	Yes	Yes	
Dual supply operation	Yes	Yes	
Turn on time max. (ns)	130	130	
Crosstalk and off isolation	-72	-72	

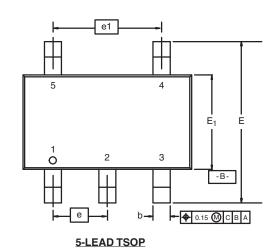
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?73854">www.vishay.com/ppg?73854</a>.

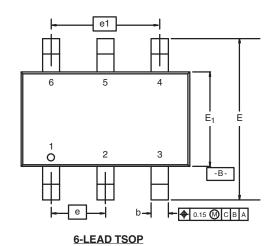


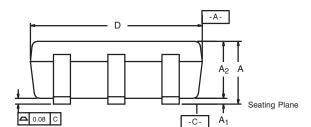


TSOP: 5/6-LEAD

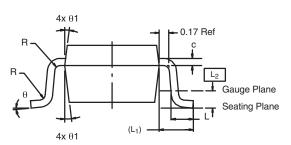
**JEDEC Part Number: MO-193C** 







-C- A<sub>1</sub>



	MIL	LIMETER	RS	ı	NCHES	
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.91	-	1.10	0.036	-	0.043
A <sub>1</sub>	0.01	-	0.10	0.0004	-	0.004
A <sub>2</sub>	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
С	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E <sub>1</sub>	1.55	1.65	1.70	0.061	0.065	0.067
е		0.95 BSC		0.0374 BSC		
e <sub>1</sub>	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L <sub>1</sub>	0.60 Ref 0.024 Ref					
L <sub>2</sub>	0.25 BSC 0.010 BSC					
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
$\theta_1$	7° Nom 7° Nom					
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540						

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